## 60MHz Rail-to-Rail Input-Output Op Amps

The EL5111, EL5211, and EL5411 are low power, high voltage rail-to-rail input-output amplifiers. The EL5111 represents a single amplifier, the EL5211 contains two amplifiers, and the EL5411 contains four amplifiers. Operating on supplies ranging from 5 V to 15 V , while consuming only 2.5 mA per amplifier, the EL5111, EL5211, and EL5411 have a bandwidth of $60 \mathrm{MHz}(-3 \mathrm{~dB})$. They also provide common mode input ability beyond the supply rails, as well as rail-to-rail output capability. This enables these amplifiers to offer maximum dynamic range at any supply voltage.

The EL5111, EL5211, and EL5411 also feature fast slewing and settling times, as well as a high output drive capability of 65 mA (sink and source). These features make these amplifiers ideal for high speed filtering and signal conditioning application. Other applications include battery power, portable devices, and anywhere low power consumption is important.

The EL5111 is available in 5 -pin TSOT and 8-pin HMSOP packages. The EL5211 is available in the 8-pin HMSOP package. The EL5411 is available in space-saving 14-pin HTSSOP packages. All feature a standard operational amplifier pinout. These amplifiers operate over a temperature range of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$.

## Features

- Pb-Free Available (RoHS Compliant)
- $60 \mathrm{MHz}-3 \mathrm{~dB}$ bandwidth
- Supply voltage $=4.5 \mathrm{~V}$ to 16.5 V
- Low supply current (per amplifier) $=2.5 \mathrm{~mA}$
- High slew rate $=75 \mathrm{~V} / \mu \mathrm{s}$
- Unity-gain stable
- Beyond the rails input capability
- Rail-to-rail output swing
- $\pm 180 \mathrm{~mA}$ output short current


## Applications

- TFT-LCD panels
- $\mathrm{V}_{\mathrm{COM}}$ amplifiers
- Drivers for A-to-D converters
- Data acquisition
- Video processing
- Audio processing
- Active filters
- Test equipment
- Battery-powered applications
- Portable equipment


## Pinouts

EL5111 (8-PIN HMSOP) TOP VIEW


EL5111 (5-PIN TSOT) TOP VIEW


EL5211
(8-PIN HMSOP)
TOP VIEW


EL5411 (14-PIN HTSSOP) TOP VIEW


## Ordering Information

| PART NUMBER | PACKAGE | TAPE \& REEL | PKG. DWG. \# |
| :---: | :---: | :---: | :---: |
| EL5111IWT-T7 | 5-Pin TSOT | 7" (3K pcs) | MDP0049 |
| EL5111IWT-T7A | 5-Pin TSOT | 7" (250 pcs) | MDP0049 |
| EL5111IWTZ-T7 <br> (Note) | 5-Pin TSOT (Pb-Free) | 7" (3K pcs) | MDP0049 |
| EL5111IWTZ-T7A <br> (Note) | 5-Pin TSOT (Pb-Free) | 7" (250 pcs) | MDP0049 |
| EL5111IYE | 8-Pin HMSOP | - | MDP0050 |
| EL5111IYE-T7 | 8-Pin HMSOP | 7" | MDP0050 |
| EL5111IYE-T13 | 8-Pin HMSOP | $13 "$ | MDP0050 |
| EL5111IYEZ (See Note) | 8-Pin HMSOP (Pb-free) | - | MDP0050 |
| EL5111IYEZ-T7 (See Note) | 8-Pin HMSOP (Pb-free) | $7 "$ | MDP0050 |
| EL5111IYEZ-T13 <br> (See Note) | 8-Pin HMSOP (Pb-free) | 13" | MDP0050 |
| EL5211IYE | 8-Pin HMSOP | - | MDP0050 |
| EL5211IYE-T7 | 8-Pin HMSOP | $7 "$ | MDP0050 |
| EL5211IYE-T13 | 8-Pin HMSOP | 13 " | MDP0050 |
| EL5211IYEZ (Note) | 8-Pin HMSOP (Pb-Free) | - | MDP0050 |
| EL5211IYEZ-T7 (Note) | 8-Pin HMSOP (Pb-Free) | $7 "$ | MDP0050 |
| $\begin{aligned} & \text { EL5211IYEZ-T13 } \\ & \text { (Note) } \end{aligned}$ | 8-Pin HMSOP (Pb-Free) | 13" | MDP0050 |
| EL5411IRE | $\begin{aligned} & \text { 14-Pin } \\ & \text { HTSSOP } \end{aligned}$ | - | MDP0048 |
| EL5411IRE-T7 | $\begin{aligned} & \text { 14-Pin } \\ & \text { HTSSOP } \end{aligned}$ | $7 "$ | MDP0048 |
| EL5411IRE-T13 | $\begin{aligned} & \text { 14-Pin } \\ & \text { HTSSOP } \end{aligned}$ | 13" | MDP0048 |
| EL5411IREZ (Note) | 14-Pin HTSSOP (Pb-Free) | - | MDP0048 |
| EL5411IREZ-T7 <br> (Note) | 14-Pin HTSSOP (Pb-Free) | $7 "$ | MDP0048 |
| EL5411IREZ-T13 (Note) | 14-Pin HTSSOP (Pb-Free) | $13 "$ | MDP0048 |

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and $100 \%$ matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb -free soldering operations. Intersil Pb -free products are MSL classified at Pb -free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020C.

```
Absolute Maximum Ratings \(\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right)\)
```



```
Input Voltage . . . . . . . . . . . . . . . . . . . . . . . . . . . \(\mathrm{V}_{\mathrm{S}}-0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}+0.5 \mathrm{~V}\)
Maximum Continuous Output Current . . . . . . . . . . . . . . . . . . . 65mA
Maximum Die Temperature . . . . . . . . . . . . . . . . . . . . . . . . . . \(+125^{\circ} \mathrm{C}\)
```

Storage Temperature . . . . . . . . . . . . . . . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Ambient Operating Temperature . . . . . . . . . . . . . . . . . $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Power Dissipation . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . See Curves

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_{J}=T_{C}=T_{A}$
Electrical Specifications $V_{S^{+}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified

| PARAMETER | DESCRIPTION | CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OS }}$ | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 3 | 15 | mV |
| TCV ${ }_{\text {OS }}$ | Average Offset Voltage Drift (Note 1) |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 2 | 60 | nA |
| $\mathrm{R}_{\text {IN }}$ | Input Impedance |  |  | 1 |  | $\mathrm{G} \Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -5.5 |  | +5.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -5.5 V to 5.5 V | 50 | 70 |  | dB |
| AVOL | Open-Loop Gain | $-4.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.5 \mathrm{~V}$ | 62 | 70 |  | dB |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | Output Swing Low | $\mathrm{L}_{\mathrm{L}}=-5 \mathrm{~mA}$ |  | -4.92 | -4.85 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{L}_{\mathrm{L}}=5 \mathrm{~mA}$ | 4.85 | 4.92 |  | V |
| Isc | Short-Circuit Current |  |  | $\pm 180$ |  | mA |
| Iout | Output Current |  |  | $\pm 65$ |  | mA |
| POWER SUPPLY PERFORMANCE |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from $\pm 2.25 \mathrm{~V}$ to $\pm 7.75 \mathrm{~V}$ | 60 | 80 |  | dB |
| Is | Supply Current | No load (EL5111) |  | 2.5 | 4.5 | mA |
|  |  | No load (EL5211) |  | 5 | 7.5 | mA |
|  |  | No load (EL5411) |  | 10 | 15 | mA |
| DYNAMIC PERFORMANCE |  |  |  |  |  |  |
| SR | Slew Rate (Note 2) | $-4.0 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.0 \mathrm{~V}, 20 \%$ to $80 \%$ |  | 75 |  | V/ $/$ s |
| ts | Settling to $+0.1 \%\left(\mathrm{~A}_{V}=+1\right)$ | $\left(\mathrm{A}_{\mathrm{V}}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ step |  | 80 |  | ns |
| BW | -3dB Bandwidth |  |  | 60 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 32 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | 。 |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ (EL5211 \& EL5411 only) |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain (Note 3) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.17 |  | \% |
| $\mathrm{d}_{\mathrm{P}}$ | Differential Phase (Note 3) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.24 |  | 。 |

NOTES:

1. Measured over operating temperature range.
2. Slew rate is measured on rising and falling edges.
3. NTSC signal generator used.

Electrical Specifications $\mathrm{V}_{\mathrm{S}^{+}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified

| PARAMETER | DESCRIPTION | CONDITION | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |  |
| V OS | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$ |  | 3 | 15 | mV |
| TCV ${ }_{\text {OS }}$ | Average Offset Voltage Drift (Note 4) |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$ |  | 2 | 60 | nA |
| $\mathrm{R}_{\mathrm{IN}}$ | Input Impedance |  |  | 1 |  | $\mathrm{G} \Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -0.5 |  | +5.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -0.5 V to 5.5 V | 45 | 66 |  | dB |
| Avol | Open-Loop Gain | $0.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.5 \mathrm{~V}$ | 62 | 70 |  | dB |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | Output Swing Low | $\mathrm{I}_{\mathrm{L}}=-5 \mathrm{~mA}$ |  | 80 | 150 | mV |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{L}_{\mathrm{L}}=5 \mathrm{~mA}$ | 4.85 | 4.92 |  | V |
| ISC | Short-circuit Current |  |  | $\pm 180$ |  | mA |
| Iout | Output Current |  |  | $\pm 65$ |  | mA |
| POWER SUPPLY PERFORMANCE |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from 4.5 V to 15.5 V | 60 | 80 |  | dB |
| Is | Supply Current | No load (EL5111) |  | 2.5 | 4.5 | mA |
|  |  | No load (EL5211) |  | 5 | 7.5 | mA |
|  |  | No load (EL5411) |  | 10 | 15 | mA |
| DYNAMIC PERFORMANCE |  |  |  |  |  |  |
| SR | Slew Rate (Note 5) | $1 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4 \mathrm{~V}, 20 \%$ to $80 \%$ |  | 75 |  | V/us |
| ts | Settling to $+0.1 \%\left(\mathrm{~A}_{V}=+1\right)$ | $\left(A_{V}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ step |  | 80 |  | ns |
| BW | -3dB Bandwidth |  |  | 60 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 32 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | - |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ (EL5211 \& EL5411 only) |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain (Note 6) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.17 |  | \% |
| $\mathrm{d}_{\mathrm{P}}$ | Differential Phase (Note 6) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.24 |  | 。 |

NOTES:
4. Measured over operating temperature range.
5. Slew rate is measured on rising and falling edges.
6. NTSC signal generator used.

Electrical Specifications $\quad \mathrm{V}_{\mathrm{S}^{+}}=+15 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $7.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified

| PARAMETER | DESCRIPTION | CONDITION | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |  |
| V OS | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=7.5 \mathrm{~V}$ |  | 3 | 15 | mV |
| TCV ${ }_{\text {OS }}$ | Average Offset Voltage Drift (Note 7) |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=7.5 \mathrm{~V}$ |  | 2 | 60 | nA |
| RIN | Input Impedance |  |  | 1 |  | $\mathrm{G} \Omega$ |

## Electrical Specifications $\quad \mathrm{V}_{\mathrm{S}^{+}}=+15 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $7.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified (Continued)

| PARAMETER | DESCRIPTION | CONDITION | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -0.5 |  | +15.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -0.5 V to 15.5 V | 53 | 72 |  | dB |
| AVOL | Open-Loop Gain | $0.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 14.5 \mathrm{~V}$ | 62 | 70 |  | dB |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | Output Swing Low | $\mathrm{L}_{\mathrm{L}}=-5 \mathrm{~mA}$ |  | 80 | 150 | mV |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA}$ | 14.85 | 14.92 |  | V |
| Isc | Short-circuit Current |  |  | $\pm 180$ |  | mA |
| lout | Output Current |  |  | $\pm 65$ |  | mA |
| POWER SUPPLY PERFORMANCE |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from 4.5V to 15.5 V | 60 | 80 |  | dB |
| Is | Supply Current | No load (EL5111) |  | 2.5 | 4.5 | mA |
|  |  | No load (EL5211) |  | 5 | 7.5 | mA |
|  |  | No load (EL5411) |  | 10 | 15 | mA |
| DYNAMIC PERFORMANCE |  |  |  |  |  |  |
| SR | Slew Rate (Note 8) | $1 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 14 \mathrm{~V}, 20 \%$ to $80 \%$ |  | 75 |  | $\mathrm{V} / \mathrm{\mu s}$ |
| $\mathrm{t}_{5}$ | Settling to $+0.1 \%\left(\mathrm{~A}_{V}=+1\right)$ | $\left(A_{V}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ step |  | 80 |  | ns |
| BW | -3dB Bandwidth |  |  | 60 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 32 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | - |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ (EL5211 \& EL5411 only) |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain (Note 9) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.16 |  | \% |
| $\mathrm{d}_{\mathrm{P}}$ | Differential Phase (Note 9) | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.22 |  | - |

NOTES:
7. Measured over operating temperature range
8. Slew rate is measured on rising and falling edges
9. NTSC signal generator used

## Typical Performance Curves



FIGURE 1. INPUT OFFSET VOLTAGE DISTRIBUTION


FIGURE 3. INPUT OFFSET VOLTAGE vs TEMPERATURE


FIGURE 5. OUTPUT HIGH VOLTAGE vs TEMPERATURE


INPUT OFFSET VOLTAGE DRIFT, $\mathrm{TCV}_{\mathrm{OS}}\left(\mu \mathrm{V} /{ }^{\circ} \mathrm{C}\right)$

FIGURE 2. INPUT OFFSET VOLTAGE DRIFT


FIGURE 4. INPUT BIAS CURRENT vs TEMPERATURE


FIGURE 6. OUTPUT LOW VOLTAGE vs TEMPERATURE


FIGURE 7. OPEN-LOOP GAIN vs TEMPERATURE


FIGURE 9. SUPPLY CURRENT PER AMPLIFIER vs SUPPLY VOLTAGE


FIGURE 11. DIFFERENTIAL GAIN


FIGURE 8. SLEW RATE vs TEMPERATURE


FIGURE 10. SUPPLY CURRENT PER AMPLIFIER vs TEMPERATURE


FIGURE 12. DIFFERENTIAL PHASE


FIGURE 13. HARMONIC DISTORTION vs $\mathrm{V}_{\text {OP-P }}$


FIGURE 15. FREQUENCY RESPONSE FOR VARIOUS $R_{L}$


FIGURE 17. CLOSED LOOP OUTPUT IMPEDANCE


FIGURE 14. OPEN LOOP GAIN AND PHASE


FIGURE 16. FREQUENCY RESPONSE FOR VARIOUS $C_{L}$


FIGURE 18. MAXIMUM OUTPUT SWING vs FREQUENCY

## Typical Performance Curves (Continued)



FIGURE 19. CMRR


FIGURE 21. INPUT VOLTAGE NOISE SPECTRAL DENSITY


FIGURE 23. SMALL-SIGNAL OVERSHOOT vs LOAD CAPACITANCE


FIGURE 20. PSRR


FIGURE 22. CHANNEL SEPARATION


FIGURE 24. SETTLING TIME vs STEP SIZE

## Typical Performance Curves (Continued)



FIGURE 25. LARGE SIGNAL TRANSIENT RESPONSE


50ns/DIV
FIGURE 26. SMALL SIGNAL TRANSIENT RESPONSE

## Pin Descriptions

| $\begin{aligned} & \text { EL5111 } \\ & \text { (TSOT-5) } \end{aligned}$ | $\begin{aligned} & \text { EL5111 } \\ & \text { (HMSOP8) } \end{aligned}$ | $\begin{aligned} & \text { EL5211 } \\ & \text { (HMSOP8) } \end{aligned}$ | $\begin{gathered} \text { EL5411 } \\ \text { ( HTSSOP14) } \end{gathered}$ | NAME | FUNCTION | EQUIVALENT CIRCUIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | 6 | 1 | 1 | VOUTA | Amplifier A output | CIRCUIT 1 |
| 4 | 2 | 2 | 2 | VINA- | Amplifier A inverting input |  |
| 3 | 3 | 3 | 3 | VINA+ | Amplifier A non-inverting input | (Reference Circuit 2) |
| 5 | 7 | 8 | 4 | VS+ | Positive power supply |  |
|  |  | 5 | 5 | VINB+ | Amplifier B non-inverting input | (Reference Circuit 2) |
|  |  | 6 | 6 | VINB- | Amplifier B inverting input | (Reference Circuit 2) |
|  |  | 7 | 7 | VOUTB | Amplifier B output | (Reference Circuit 1) |
|  |  |  | 8 | VOUTC | Amplifier C output | (Reference Circuit 1) |
|  |  |  | 9 | VINC- | Amplifier C inverting input | (Reference Circuit 2) |
|  |  |  | 10 | VINC+ | Amplifier C non-inverting input | (Reference Circuit 2) |
| 2 | 4 | 4 | 11 | VS- | Negative power supply |  |
|  |  |  | 12 | VIND+ | Amplifier D non-inverting input | (Reference Circuit 2) |
|  |  |  | 13 | VIND- | Amplifier D inverting input | (Reference Circuit 2) |
|  |  |  | 14 | VOUTD | Amplifier D output | (Reference Circuit 1) |
|  | 1, 5, 8 |  |  | NC | Not connected |  |

## Applications Information

## Product Description

The EL5111, EL5211, and EL5411 voltage feedback amplifiers are fabricated using a high voltage CMOS process. They exhibit rail-to-rail input and output capability, are unity gain stable and have low power consumption (2.5mA per amplifier). These features make the EL5111, EL5211, and EL5411 ideal for a wide range of generalpurpose applications. Connected in voltage follower mode and driving a load of $1 \mathrm{k} \Omega$, the EL5111, EL5211, and EL5411 have a -3 dB bandwidth of 60 MHz while maintaining a $75 \mathrm{~V} / \mu \mathrm{s}$ slew rate. The EL5111 is a single amplifier, the EL5211 a dual amplifier, and the EL5411 a quad amplifier.

## Operating Voltage, Input, and Output

The EL5111, EL5211, and EL5411 are specified with a single nominal supply voltage from 5 V to 15 V or a split supply with its total range from 5 V to 15 V . Correct operation is guaranteed for a supply range of 4.5 V to 16.5 V . Most EL5111, EL5211, and EL5411 specifications are stable over both the full supply range and operating temperatures of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$. Parameter variations with operating voltage and/or temperature are shown in the typical performance curves.

The input common-mode voltage range of the EL5111, EL5211, and EL5411 extends 500 mV beyond the supply rails. The output swings of the EL5111, EL5211, and EL5411 typically extend to within 100 mV of positive and negative supply rails with load currents of 5 mA . Decreasing load currents will extend the output voltage range even closer to the supply rails. Figure 27 shows the input and output waveforms for the device in the unity-gain configuration. Operation is from $\pm 5 \mathrm{~V}$ supply with a $1 \mathrm{k} \Omega$ load connected to GND. The input is a $10 \mathrm{~V}_{\mathrm{P}-\mathrm{P}}$ sinusoid. The output voltage is approximately $9.8 \mathrm{~V}_{\mathrm{P}-\mathrm{P}}$.

$$
V_{S}= \pm 5 \mathrm{~V}, \mathrm{~T}_{A}=25^{\circ} \mathrm{C}, A_{V}=1, \mathrm{~V}_{\mathrm{IN}}=10 \mathrm{~V}_{\mathrm{P}-\mathrm{P}}
$$



OUTPUT INPUT
FIGURE 27. OPERATION WITH RAIL-TO-RAIL INPUT AND OUTPUT

## Short Circuit Current Limit

The EL5111, EL5211, and EL5411 will limit the short circuit current to $\pm 180 \mathrm{~mA}$ if the output is directly shorted to the positive or the negative supply. If an output is shorted
indefinitely, the power dissipation could easily increase such that the device may be damaged. Maximum reliability is maintained if the output continuous current never exceeds $\pm 65 \mathrm{~mA}$. This limit is set by the design of the internal metal interconnects.

## Output Phase Reversal

The EL5111, EL5211, and EL5411 are immune to phase reversal as long as the input voltage is limited from $\mathrm{V}_{\mathrm{S}}-0.5 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{S}^{+}}+0.5 \mathrm{~V}$. Figure 28 shows a photo of the output of the device with the input voltage driven beyond the supply rails. Although the device's output will not change phase, the input's overvoltage should be avoided. If an input voltage exceeds supply voltage by more than 0.6 V , electrostatic protection diodes placed in the input stage of the device begin to conduct and overvoltage damage could occur.


FIGURE 28. OPERATION WITH BEYOND-THE-RAILS INPUT

## Power Dissipation

With the high-output drive capability of the EL5111, EL5211, and EL5411 amplifiers, it is possible to exceed the $125^{\circ} \mathrm{C}$ 'absolute-maximum junction temperature' under certain load current conditions. Therefore, it is important to calculate the maximum junction temperature for the application to determine if load conditions need to be modified for the amplifier to remain in the safe operating area.

The maximum power dissipation allowed in a package is determined according to:
$P_{\text {DMAX }}=\frac{T_{J M A X}-T_{A M A X}}{\Theta_{J A}}$
where:

- $\mathrm{T}_{\text {JMAX }}=$ Maximum junction temperature
- TAMAX $=$ Maximum ambient temperature
- $\Theta_{J A}=$ Thermal resistance of the package
- $P_{\text {DMAX }}=$ Maximum power dissipation in the package

The maximum power dissipation actually produced by an IC is the total quiescent supply current times the total power supply voltage, plus the power in the IC due to the loads, or:
$P_{\text {DMAX }}=\Sigma \mathrm{i}\left[\mathrm{V}_{\mathrm{S}} \times \mathrm{I}_{\text {SMAX }}+\left(\mathrm{V}_{\mathrm{S}^{+}}-\mathrm{V}_{\text {OUT }} \mathrm{i}\right) \times \mathrm{I}_{\text {LOAD }}{ }^{\mathrm{i}}\right]$
when sourcing, and:
$\mathrm{P}_{\text {DMAX }}=\Sigma \mathrm{i}\left[\mathrm{V}_{\mathrm{S}} \times \mathrm{I}_{\text {SMAX }}+\left(\mathrm{V}_{\text {OUT }}{ }^{\mathrm{i}}-\mathrm{V}_{\mathrm{S}^{-}}\right) \times \mathrm{I}_{\text {LOAD }}{ }^{\mathrm{i}}\right]$
when sinking,
where:

- $\mathrm{i}=1$ to 2 for dual and 1 to 4 for quad
- $\mathrm{V}_{\mathrm{S}}=$ Total supply voltage
- ISMAX = Maximum supply current per amplifier
- $\mathrm{V}_{\text {OUT }}{ }^{\mathrm{i}}=$ Maximum output voltage of the application
- LloADi = Load current

If we set the two $P_{\text {DMAX }}$ equations equal to each other, we can solve for $R_{\text {LOAD }}$ to avoid device overheat. Figures 29, 30 , and 31 provide a convenient way to see if the device will overheat. The maximum safe power dissipation can be found graphically, based on the package type and the ambient temperature. By using the previous equation, it is a simple matter to see if $P_{\text {DMAX }}$ exceeds the device's power derating curves. To ensure proper operation, it is important to observe the recommended derating curves shown in Figures 29, 30 \& 31.


FIGURE 29. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

JEDEC JESD51-7 HIGH EFFECTIVE THERMAL CONDUCTIVITY (4-LAYER) TEST BOARD HTSSOP EXPOSED DIEPAD SOLDERED TO PCB PER JESD51-5


FIGURE 30. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

## Unused Amplifiers

It is recommended that any unused amplifiers in a dual and a quad package be configured as a unity gain follower. The inverting input should be directly connected to the output and the non-inverting input tied to the ground plane.

## Power Supply Bypassing and Printed Circuit Board Layout

The EL5111, EL5211, and EL5411 can provide gain at high frequency. As with any high-frequency device, good printed circuit board layout is necessary for optimum performance. Ground plane construction is highly recommended, lead lengths should be as short as possible and the power supply pins must be well bypassed to reduce the risk of oscillation. For normal single supply operation, where the $\mathrm{V}_{\mathrm{S}^{-}}$pin is connected to ground, a $0.1 \mu \mathrm{~F}$ ceramic capacitor should be placed from $\mathrm{V}_{\mathrm{S}^{+}}$to pin to $\mathrm{V}_{\mathrm{S}^{-}}$pin. A $4.7 \mu \mathrm{~F}$ tantalum capacitor should then be connected in parallel, placed in the region of the amplifier. One $4.7 \mu \mathrm{~F}$ capacitor may be used for multiple devices. This same capacitor combination should be placed at each supply pin to ground if split supplies are to be used.

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